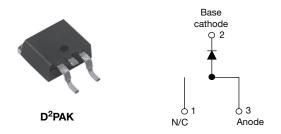


VS-12TQ035SPbF, VS-12TQ040SPbF, VS-12TQ045SPbF

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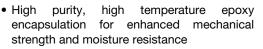
High Performance Schottky Rectifier, 15 A



PRODUCT SUMMARY					
Package	D ² PAK				
I _{F(AV)}	15 A				
V _R	35 V, 40 V, 45 V				
V _F at I _F	0.50 V				
I _{RM}	70 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Single die				
E _{AS}	16 mJ				

FEATURES

- 150 °C T_J operation
- · Very low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-12TQ...SPbF Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	15	Α			
V _{RRM}	Range	35 to 45	V			
I _{FSM}	$t_p = 5 \mu s sine$	990	Α			
V _F	15 A _{pk} , T _J = 125 °C	0.50	V			
T _J	Range	-55 to +150	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-12TQ035SPbF	VS-12TQ040SPbF	VS-12TQ045SPbF	UNITS
Maximum DC reverse voltage	V_R	35	40	45	V
Maximum working peak reverse voltage	V_{RWM}	33	40	45	V

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS			
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 120 °C, rectangular waveform		15	А	
Maximum peak one cycle non-repetitive surge current	l	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	990	А	
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	250		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2.4 A, L = 5.5 mH		16	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to ze Frequency limited by T _J maxim		2.4	А	

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		15 A	T 05.00	0.56	V
Maximum forward voltage drop	V (1)	30 A	- T _J = 25 °C	0.71	
See fig. 1	V _{FM} ⁽¹⁾	15 A	T 105 °C	0.50	
		30 A	- T _J = 125 °C	0.64	
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	1.75	mA
See fig. 2		T _J = 125 °C	v _R = nateu v _R	70	l IIIA
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	ge 100 kHz to 1 MHz), 25 °C	900	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	2.0	°C/W	
Typical thermal resistant case to heatsink			Mounting surface, smooth and greased	0.50	C/VV	
A nove vine et e ve i eht				2	g	
Approximate weight				0.07	oz.	
Mounting town	minimum			6 (5)	kgf · cm	
Mounting torque -	maximum			12 (10)	(lbf · in)	
Marking device			Case style D ² PAK	12TQ	045S	

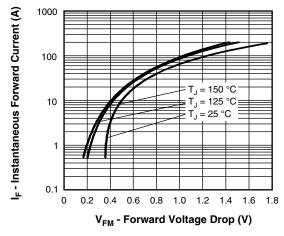


Fig. 1 - Maximum Forward Voltage Drop Characteristics

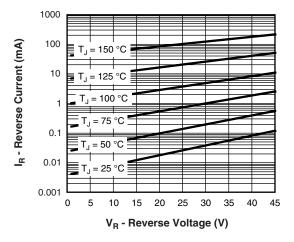


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

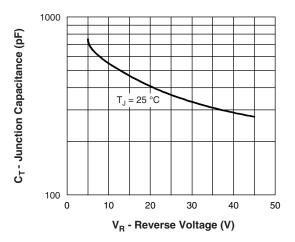


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

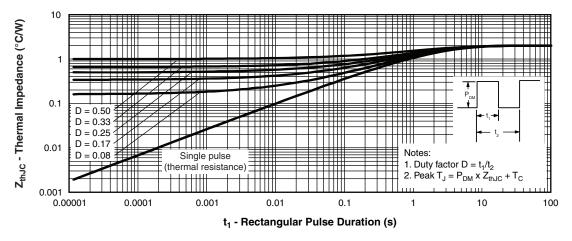


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

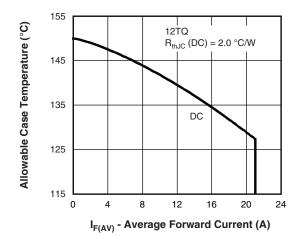


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

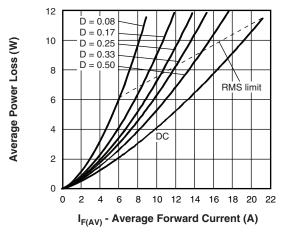
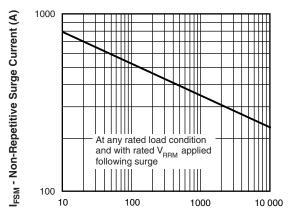


Fig. 6 - Forward Power Loss Characteristics

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t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

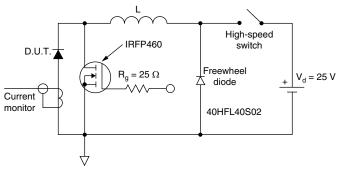
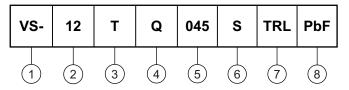


Fig. 8 - Unclamped Inductive Test Circuit

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating
- 3 Package: T = TO-220
- Schottky "Q" series 035 = 35 V
- 5 Voltage ratings 040 = 40 V 045 = 45 V
- 7 • None = tube (50 pieces)
 - TRL = tape and reel (left oriented)
 - TRR = tape and reel (right oriented)
- 8 PbF = lead (Pb)-free

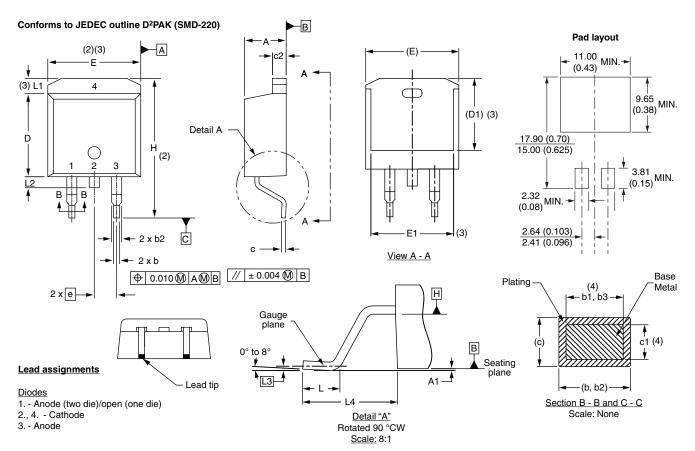
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95014</u>					
Part marking information	www.vishay.com/doc?95008				
Packaging information	www.vishay.com/doc?95032				



Vishay High Power Products

D²PAK, TO-262

DIMENSIONS FOR D²PAK in millimeters and inches



	MILLIM	IETERS	INC		
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
Е	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

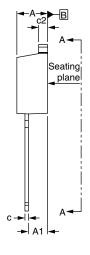
(7) Outline conforms to JEDEC outline TO-263AB

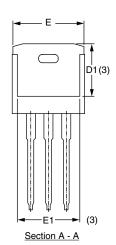
Vishay High Power Products

D²PAK, TO-262



DIMENSIONS FOR TO-262 in millimeters and inches





⊕ 0.010**⋒**|A**⋒**|B

Lead assignments



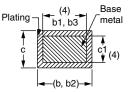
Diodes

-3 x b2 --3 x b

1. - Anode (two die)/open (one die)

2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIMETERS		INC	INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100) BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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